## PROCEEDINGS OF SPIE

# Oxide-based Materials and Devices XIV

David J. Rogers Ferechteh H. Teherani Editors

30 January – 2 February 2023 San Francisco, California, United States

Sponsored and Published by SPIE

Volume 12422

Proceedings of SPIE 0277-786X, V. 12422

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Oxide-based Materials and Devices XIV, edited by David J. Rogers, Ferechteh H. Teherani, Proc. of SPIE Vol. 12422, 124220Z © 2023 SPIE · 0277-786X · doi: 10.1117/12.2683761

Proc. of SPIE Vol. 12422 124220Z-1

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ISSN: 0277-786X ISSN: 1996-756X (electronic)

ISBN: 9781510659490 ISBN: 9781510659506 (electronic)

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